## NSN 5962-01-263-5905

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-263-5905 **Body Length:** 0.540 inches **Body Width:** Between 0.245 inches and 0.300 inches **Body Height:** Between 0.045 inches and 0.092 inches **Maximum Power Dissipation Rating:** 176.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Synchronous and hermetically sealed and monolithic and schottky and low power and 3-state output **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 12 input **Case Outline Source And Designator:** F-9 mil-m-38510 **Terminal Surface Treatment:** Gold or solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Memory Device Type:** Rom **Precious Material And Location:** Terminal surfaces option gold **Precious Material:** Gold **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.). **Terminal Type And Quantity:** 20 flat leads Shelf Life: N/a

**Unit Of Measure:** 

## NSN 5962-01-263-5905

Memory Microcircuit - Page 2 of 2



Demilitarization:

Yes - demil/mli

Fiig:

A458a0